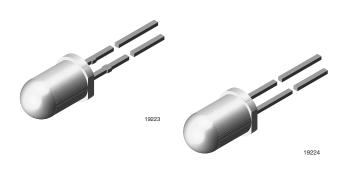


Vishay Semiconductors

High Intensity LED, ∅ 5 mm Tinted Diffused



DESCRIPTION

This LED contains the double heterojunction (DH) GaAlAs on GaAs technology.

This deep red LED can be utilized over a wide range of drive current. It can be DC or pulse driven to achieve desired light output.

The device is available in a tinted diffused 5 mm package with a wide radiation angle.

PRODUCT GROUP AND PACKAGE DATA

Product group: LEDPackage: 5 mm

Product series: standard
Angle of half intensity: ± 30°

FEATURES

- Exceptional brightness
- · Wide viewing angle
- · Low forward voltage
- 5 mm (T-1¾") tinted diffused package
- · Deep red color
- · Very high intensity even at low drive currents
- · Categorized for luminous intensity
- · Outstanding material efficiency
- · Lead (Pb)-free device
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

- Bright ambient lighting conditions
- · Battery powered equipment
- · Indoor and outdoor information displays
- Portable equipment
- · Telecommunication indicators
- · General use

PARTS TABLE					
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY			
TLDR5400/6400	Red, I _V ≥ 35 mcd	GaAlAs on GaAs			

ABSOLUTE MAXIMUM RATINGS ¹⁾ TLDR5400/TLDR6400					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage ²⁾		V _R	6	V	
DC Forward current		I _F	50	mA	
Surge forward current	t _p ≤ 10 μs	I _{FSM}	1	Α	
Power dissipation		P _V	100	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	
Storage temperature range		T _{stg}	- 55 to + 100	°C	
Soldering temperature	$t \le 5$ s, 2 mm from body	T _{sd}	260	°C	
Thermal resistance junction/ ambient		R _{thJA}	350	K/W	

Note

1) T_{amb} = 25 °C, unless otherwise specified

2) Driving the LED in reverse direction is suitable for a short term application

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OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ TLDR5400/TLDR6400, RED						
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity	I _F = 20 mA	Ι _V	35	70		mcd
Luminous intensity	I _F = 1 mA	Ι _V		3		mcd
Dominant wavelength	I _F = 20 mA	λ_{d}		648		nm
Peak wavelength	I _F = 20 mA	λ_{p}		650		nm
Spectral line half width		Δλ		20		nm
Angle of half intensity	I _F = 20 mA	φ		± 30		deg
Forward voltage	I _F = 20 mA	V _F		1.8	2.2	V
Reverse current	V _R = 6 V	I _R			10	μΑ
Junction capacitance	V _R = 0, f = 1 MHz	C _j		30		pF

Note

¹⁾ T_{amb} = 25 °C, unless otherwise specified

LUMINOUS INTENSITY CLASSIFICATION					
GROUP	LUMINOUS INTENSITY (MCD)				
STANDARD	MIN	MAX			
Tb	35	50			
U	40	80			
V	63	125			
W	100	200			
X	130	260			
Y	180	360			
Z	240	480			
AA	320	640			
BB	430	860			

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of \pm 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each bag (there will be no mixing of two groups in each bag).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one bag. In order to ensure availability, single wavelength groups will not be orderable.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

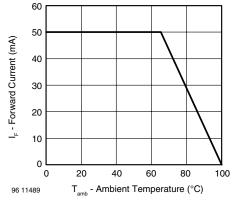


Figure 1. Forward Current vs. Ambient Temperature for AllnGaP

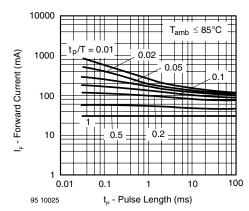


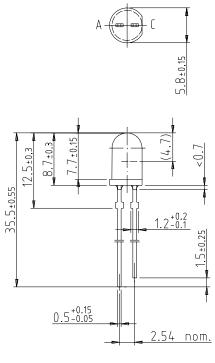
Figure 2. Forward Current vs. Pulse Length

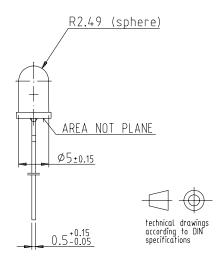
TLDR5400/TLDR6400

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PACKAGE DIMENSIONS in millimeters **TLDR5400**





95 10916

PACKAGE DIMENSIONS in millimeters **TLDR6400**

